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APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.
10/709,846	06/01/2004	Ching-Huei Tsai	NAUP0572USA	3845
27765	7590 10/18/2005		EXAMINER	
NORTH AMERICA INTELLECTUAL PROPERTY CORPORATION			HU, SHOUXIANG	
P.O. BOX 506 MERRIFIELD, VA 22116		ART UNIT	PAPER NUMBER	
			2811	
			DATE MAILED: 10/18/200	5

Please find below and/or attached an Office communication concerning this application or proceeding.

\checkmark	and	EX
V	7/2	

	Application No.	Applicant(s)					
Office Action Summer	10/709,846	TSAI, CHING-HUEI					
Office Action Summary	Examiner	Art Unit					
	Shouxiang Hu	2811					
The MAILING DATE of this communication app Period for Reply	ears on the cover sheet with the co	orrespondence address					
A SHORTENED STATUTORY PERIOD FOR REPLY IS SET TO EXPIRE 3 MONTH(S) OR THIRTY (30) DAYS, WHICHEVER IS LONGER, FROM THE MAILING DATE OF THIS COMMUNICATION. - Extensions of time may be available under the provisions of 37 CFR 1.136(a). In no event, however, may a reply be timely filed after SIX (6) MONTHS from the mailing date of this communication. - If NO period for reply is specified above, the maximum statutory period will apply and will expire SIX (6) MONTHS from the mailing date of this communication. - Failure to reply within the set or extended period for reply will, by statute, cause the application to become ABANDONED (35 U.S.C. § 133). Any reply received by the Office later than three months after the mailing date of this communication, even if timely filed, may reduce any earned patent term adjustment. See 37 CFR 1.704(b).							
Status							
1) Responsive to communication(s) filed on							
•	action is non-final.						
3) Since this application is in condition for allowan		secution as to the merits is					
•	closed in accordance with the practice under <i>Ex parte Quayle</i> , 1935 C.D. 11, 453 O.G. 213.						
Disposition of Claims							
4)⊠ Claim(s) <u>1-16</u> is/are pending in the application.							
4a) Of the above claim(s) is/are withdraw	4a) Of the above claim(s) is/are withdrawn from consideration.						
5) Claim(s) is/are allowed.							
6)⊠ Claim(s) <u>1-16</u> is/are rejected.							
7) Claim(s) is/are objected to.							
8) Claim(s) are subject to restriction and/or	election requirement.						
Application Papers							
9) The specification is objected to by the Examine	r.						
10)☐ The drawing(s) filed on is/are: a)☐ acce	epted or b) \square objected to by the E	Examiner.					
Applicant may not request that any objection to the	drawing(s) be held in abeyance. See	37 CFR 1.85(a).					
Replacement drawing sheet(s) including the correction is required if the drawing(s) is objected to. See 37 CFR 1.121(d).							
11)☐ The oath or declaration is objected to by the Ex	aminer. Note the attached Office	Action or form PTO-152.					
Priority under 35 U.S.C. § 119							
12) Acknowledgment is made of a claim for foreign priority under 35 U.S.C. § 119(a)-(d) or (f). a) All b) Some * c) None of: 1. Certified copies of the priority documents have been received.							
2. Certified copies of the priority documents have been received in Application No							
3. Copies of the certified copies of the priority documents have been received in this National Stage							
application from the International Bureau (PCT Rule 17.2(a)).							
* See the attached detailed Office action for a list of the certified copies not received.							
•							
Amasharan/a)							
Attachment(s) 1) ☑ Notice of References Cited (PTO-892) 4) ☐ Interview Summary (PTO-413)							
2) Notice of Draftsperson's Patent Drawing Review (PTO-948)							
3) Information Disclosure Statement(s) (PTO-1449 or PTO/SB/08)	5)	atent Application (PTO-152)					
Paper No(s)/Mail Date							

DETAILED ACTION

Claim Rejections - 35 USC § 102

The following is a quotation of the appropriate paragraphs of 35 U.S.C. 102 that form the basis for the rejections under this section made in this Office action:

A person shall be entitled to a patent unless -

- (b) the invention was patented or described in a printed publication in this or a foreign country or in public use or on sale in this country, more than one year prior to the date of application for patent in the United States
- 1. Claims 1-9 and 11-16 are rejected under 35 U.S.C. 102(b) as being anticipated by Applicant's admitted prior art ("AAPA").

AAPA discloses a semiconductor wafer and/or capacitor (Figs. 1-5), comprising: a silicon substrate with first, second and third regions on the substrate surface, wherein the three regions can be defined as illustrated in the attached drawing (Attachment A) and they are all on (i.e., near and/or above) the surface of the substrate; a field oxide (14); and, a capacitor on the substrate, including: a first electrode (16; polysilicon) in the first and third regions; a first isolation layer (18); and, a second electrode (22; polysilicon) in the second and third regions; a second isolation layer (26), a first contact plug (28); and, a second contact plug (32).

Claim Rejections - 35 USC § 103

The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:

(a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and

the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negatived by the manner in which the invention was made.

Claim 10 is rejected under 35 U.S.C. 103(a) as being unpatentable over AAPA.
 The disclosure of AAPA is discussed as applied to claims 1-9 and 11-16 above.

Although AAPA does not expressly disclose that the first insulation layer can be formed of silicon oxide or silicon nitride, it is noted that it is art known that each of the two materials are commonly used in the art for forming a gate dielectric layer and/or a capacitor dielectric layer for good insulation performance with desired compatible depositing process.

Therefore, it would have been obvious to one of ordinary skill in the art at the time the invention was made to make the device of AAPA with the first insulation layer being formed of the art-known commonly-used insulating material of silicon oxide or silicon nitride, so that a semiconductor device with good internal insulation performance and/or with desired compatible depositing process would be obtained.

Conclusion

3. The prior art made of record and not relied upon is considered pertinent to applicant's disclosure. References A-D are cited as being related to a capacitor structure.

Any inquiry concerning this communication or earlier communications from the examiner should be directed to Shouxiang Hu whose telephone number is 571-272-1654. The examiner can normally be reached on Monday through Thursday, 7:30 AM to 6:00 PM.

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If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Eddie C. Lee can be reached on 571-272-1732. The fax phone number for the organization where this application or proceeding is assigned is 571-273-8300.

Information regarding the status of an application may be obtained from the Patent Application Information Retrieval (PAIR) system. Status information for published applications may be obtained from either Private PAIR or Public PAIR. Status information for unpublished applications is available through Private PAIR only. For more information about the PAIR system, see http://pair-direct.uspto.gov. Should you have questions on access to the Private PAIR system, contact the Electronic Business Center (EBC) at 866-217-9197 (toll-free).

SH

October 13, 2005

SHOUXIANG HU PRIMARY EXAMINER

Attachment: Attachment A

Attachment A: 25 10 28-~ 32 25 18 24 <u>16</u> <u>26</u>< <u>14</u> <u>12</u>

Fig. 1 Prior art